Switching diode IMP11

Application

Ultra high speed switching

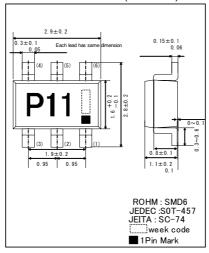
Features

- 1) Small mold type. (SMD6)
- 2) High reliability

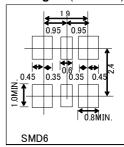
Construction

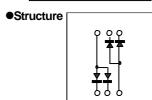
Silicon epitaxial planar

●External dimensions (Unit : mm)

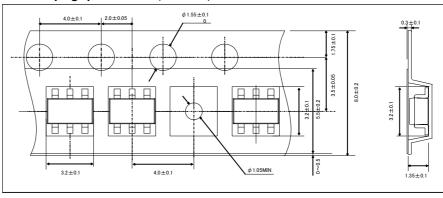


●Land size figure (Unit : mm)





● Taping specifications (Unit: mm)



● Absolute maximum ratings (Ta=25°C)

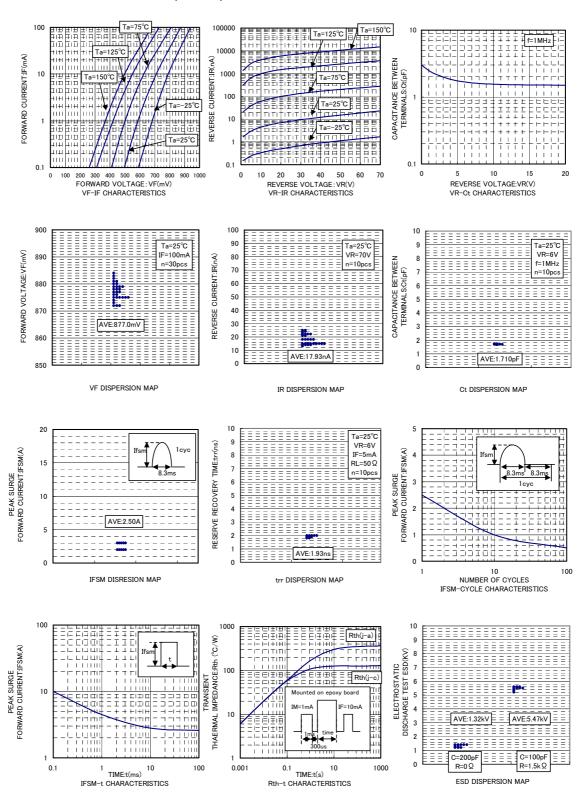
| Parameter | | 12-26- | | |
|--|--------------------|-------------|------|--|
| Parameter | Symbol | Limits | Unit | |
| Reverse voltage (repetitive peak) | V_{RM} | 80 | V | |
| Reverse voltage (DC) | V_R | 80 | V | |
| Forward current (Single) | I _{FM} | 300 | mA | |
| Average rectified forward current (Single) | Ιο | 100 | mA | |
| Surge current (t=1us) (Single) | I _{surge} | 4 | Α | |
| Power dissipation (TOTAL)(*1) | Pd | 300 | mW | |
| Junction temparature | Tj | 150 | °C | |
| Storage temperature | Tstg | -55 to +150 | °C | |

^(*1) Not exceed 200mW per element.

●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|-------------------------------|----------------|------|------|------|------|-------------------------------------|
| Forward voltagae | V_{F} | • | - | 1.2 | V | I _F =100mA |
| Reverse current | I _R | - | - | 0.1 | μA | V _R =70V |
| Capacitance between terminals | Ct | - | - | 3.5 | pF | V _R =6V , f=1MHz |
| Reverse recovery time | trr | - | - | 4 | ns | V_R =6V , IF=5mA , RL=50 Ω |

●Electrical characteristic curves (Ta=25°C)



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